DATA SHEET

# MOS FIELD EFFECT TRANSISTOR 2SK3115B

## SWITCHING N-CHANNEL POWER MOS FET

## DESCRIPTION

F

The 2SK3115B is N-Channel MOS FET device that features a low gate charge and excellent switching characteristics, and designed for high voltage applications such as switching power supply, AC adapter.

## **ORDERING INFORMATION**

PART NUMBER	PACKAGE		
2SK3115B-S17-AY Note	Isolated TO-220		

**Note** Pb-free (This product does not contain Pb in External electrode.)

## **FEATURES**

· Low gate charge

QG = 21 nC TYP. (VDD = 450 V, VGS = 10 V, ID = 6.0 A)

- Gate voltage rating :  $\pm 30 \text{ V}$
- Low on-state resistance

 $R_{DS(on)}$  = 1.2  $\Omega$  MAX. (VGs = 10 V, ID = 3.0 A)

Avalanche capability ratings

## ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (V <sub>GS</sub> = 0 V)	VDSS	600	V	
Gate to Source Voltage (VDs = 0 V)	Vgss	±30	V	
Drain Current (DC) (Tc = 25°C)	C) (Tc = $25^{\circ}$ C) ID(DC) ±6.			
Drain Current (pulse) <sup>Note1</sup>	D(pulse)	±24	А	
Total Power Dissipation (T <sub>A</sub> = 25°C)	P <sub>T1</sub>	2.0	W	
Total Power Dissipation (Tc = 25°C)	Pt2	35	W	
Channel Temperature	Tch	150	°C	
Storage Temperature	Tstg	–55 to +150	°C	
Single Avalanche Current Note2	las	6.0	А	
Single Avalanche Energy Note2	Eas	24	mJ	

(Isolated TO-220)



**Notes 1.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1%

**2.** Starting T<sub>ch</sub> = 25°C, V<sub>DD</sub> = 150 V, R<sub>G</sub> = 25  $\Omega$ , V<sub>GS</sub> = 20  $\rightarrow$  0 V

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Document No. D18065EJ2V0DS00 (2nd edition) Date Published August 2006 NS CP (K) Printed in Japan

The mark <R> shows major revised points.

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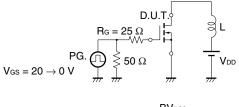
ELECTRICAL CHARACTERISTICS (TA = 25°C)

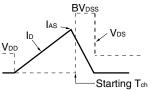
Characteristics	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> = 600 V, V <sub>GS</sub> = 0 V			100	μA
Gate Leakage Current	lgss	V <sub>GS</sub> = ±30 V, V <sub>DS</sub> = 0 V			±100	nA
Gate Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	2.5		3.5	V
Forward Transfer Admittance Note	<b>y</b> fs	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 3.0 A	2.0	2.7		S
Drain to Source On-state Resistance <sup>Note</sup>	RDS(on)	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 3.0 A		0.9	1.2	Ω
Input Capacitance	Ciss	V <sub>DS</sub> = 10 V		1090		pF
Output Capacitance	Coss	V <sub>GS</sub> = 0 V		380		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		53		pF
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> = 150 V, I <sub>D</sub> = 3.0 A		16		ns
Rise Time	tr	V <sub>GS</sub> = 10 V		11		ns
Turn-off Delay Time	t <sub>d(off)</sub>	R <sub>G</sub> = 10 Ω		29		ns
Fall Time	tr	R∟ = 50 Ω		8		ns
Total Gate Charge	QG	V <sub>DD</sub> = 450 V		21		nC
Gate to Source Charge	Q <sub>GS</sub>	V <sub>GS</sub> = 10 V		8		nC
Gate to Drain Charge	Qgd	I <sub>D</sub> = 6.0 A		8		nC
Body Diode Forward Voltage Note	VF(S-D)	IF = 6.0 A, VGS = 0 V		0.9		V
Reverse Recovery Time	trr	IF = 6.0 A, VGS = 0 V		360		ns
Reverse Recovery Charge	Qrr	di/dt = 50 A/ <i>µ</i> s		1730		nC

Note Pulsed

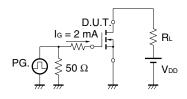
### **TEST CIRCUIT 1 AVALANCHE CAPABILITY**

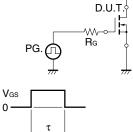
#### **TEST CIRCUIT 2 SWITCHING TIME**



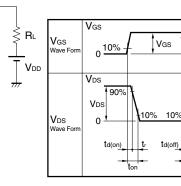


#### **TEST CIRCUIT 3 GATE CHARGE**





$$\label{eq:tau} \begin{split} \tau &= 1 \; \mu s \\ Duty \; Cycle \leq 1\% \end{split}$$



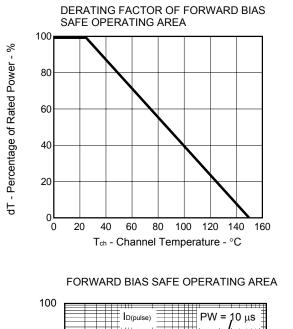
90%

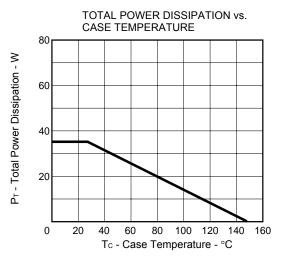
90%

tf

toff

#### TYPICAL CHARACTERISTICS (TA = 25°C)







D(DC)

R<sub>DS(on)</sub> Limited (at V<sub>GS</sub> = 10 V)

Power Dissipation

Tc = 25°C, Single pulse

10

VDS - Drain to Source Voltage - V

100

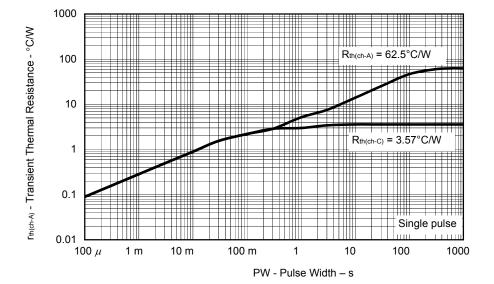
1000

10

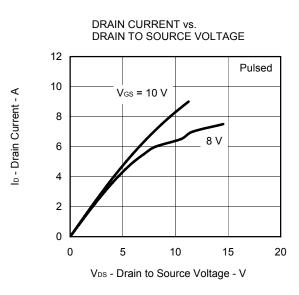
1

0.1

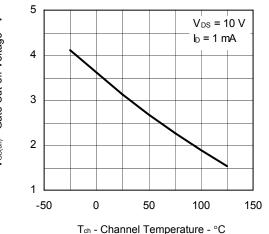
0.01 L



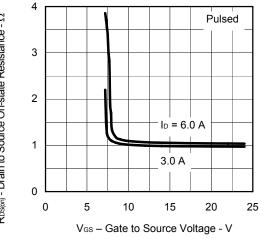
#### TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



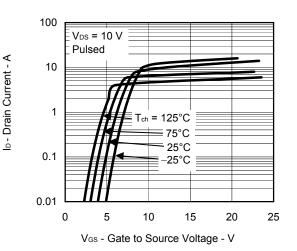




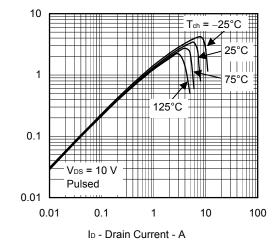




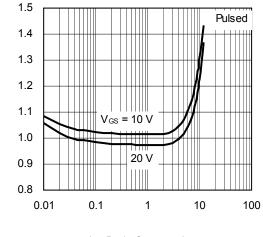
FORWARD TRANSFER CHARACTERISTICS

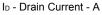


FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT





4

 $R_{\text{DS}(\text{on})}$  - Drain to Source On-state Resistance -  $\Omega$ 

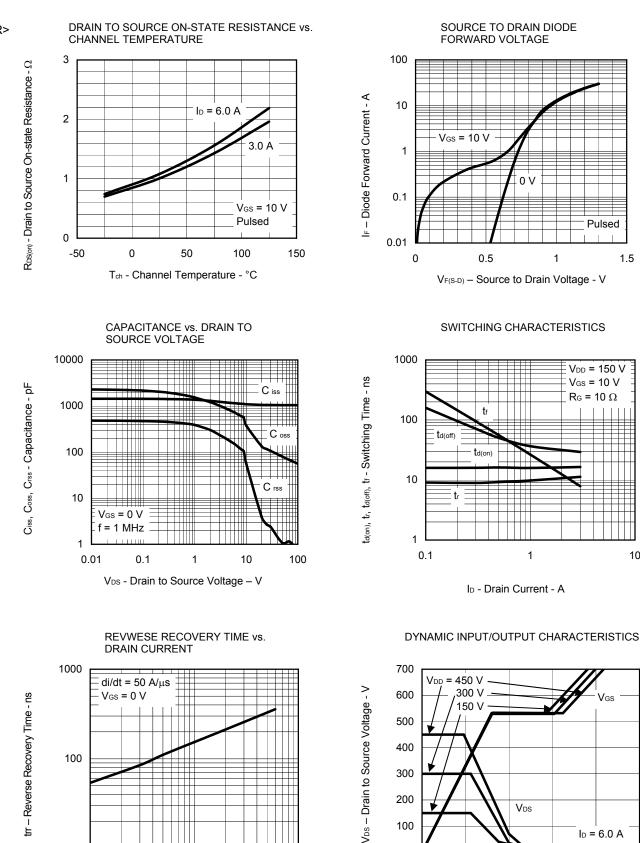
| y<sub>15</sub> | - Forward Transfer Admittance - S

1.5

I<sub>D</sub> = 6.0 A

Gate to Source Voltage - V

V<sub>GS</sub> 



<R>

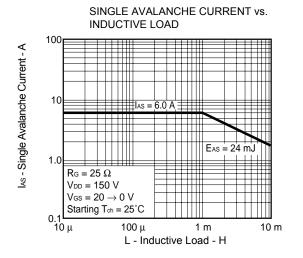
Data Sheet D18065EJ2V0DS

VDS

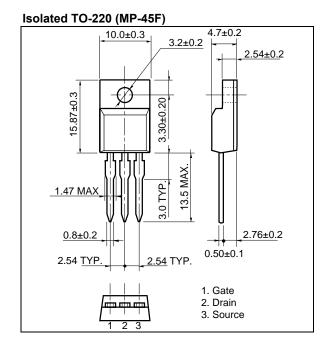
Q<sub>G</sub> – Gate Chage - nC

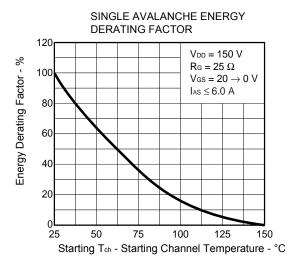
0.1

ID - Drain Current - A

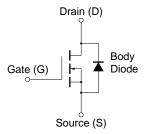


## PACKAGE DRAWING (Unit: mm)





## **EQUIVALENT CIRCUIT**



**Remark** Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

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